Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1587

Audio Frequency General Purpose Amplifier Applications

• High voltage: $V_{\rm CEO} = -120 \text{ V}$

• Excellent hFE linearity: hFE (IC = -0.1 mA)/hFE (IC = -2 mA) = 0.95 (typ.)

• High hff: hff = $200 \sim 700$

• Low noise: NF = 1dB (typ.), 10dB (max)

• Complementary to 2SC4117

Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-120	V
Collector-emitter voltage	V_{CEO}	-120	٧
Emitter-base voltage	V_{EBO}	- 5	V
Collector current	IC	-100	mA
Base current	ΙΒ	-20	mA
Collector power dissipation	PC	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	−5 5~1 25	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

1. BASE
2. EMITTER
3. COLLECTOR

JEDEC

JEITA

SC-70

TOSHIBA

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Weight: 0.006 g (typ.)

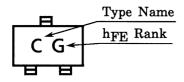
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

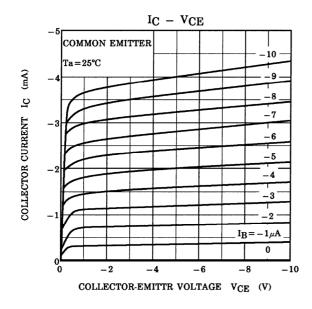
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -120 \text{ V}, I_E = 0$	_	_	-0.1	μΑ
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$		_	-0.1	μΑ
DC current gain	h _{FE} (Note)	$V_{CE} = -6 \text{ V}, I_C = -2 \text{ mA}$	200	_	700	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$	_	_	-0.3	V
Transition frequency	f _T	$V_{CE} = -6 \text{ V}, I_{C} = -1 \text{ mA}$	_	100	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	4	_	pF
Noise figure	NF	$V_{CE} = -6 \text{ V}, I_C = -0.1 \text{ mA}, f = 1 \text{ kHz},$ $Rg = 10 \text{ k}\Omega$	l	1.0	10	dB

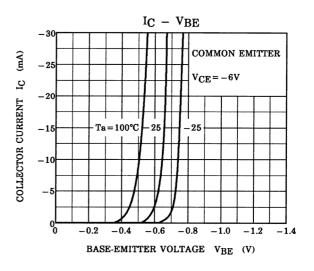
Note: h_{FE} classification GR (G): 200~400, BL (L): 350~700 () marking symbol

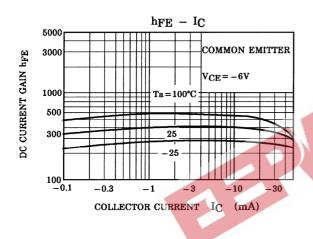
Marking

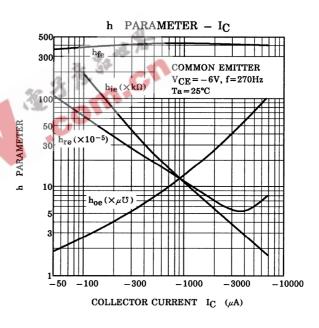


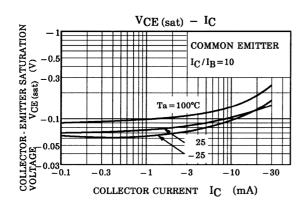
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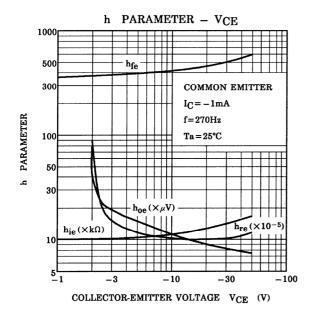


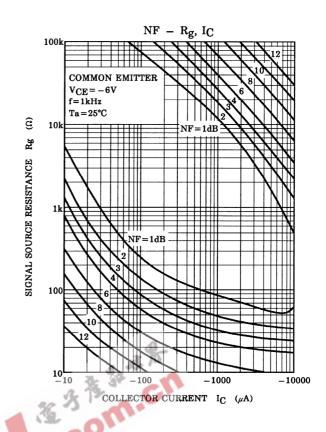


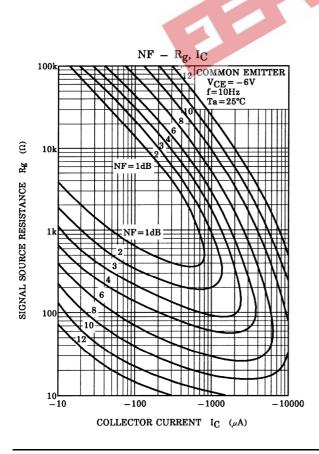


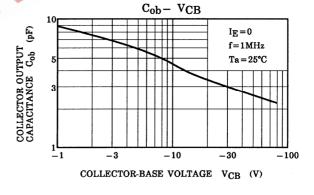


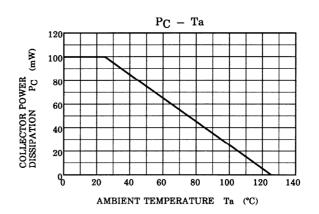
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RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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